

**30 V, 85 A, 2.1 mΩ Low RDS(ON)
N ch Trench Power MOSFET
SKI03021**

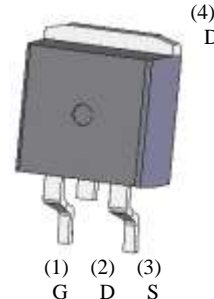


Features

- $V_{(BR)DSS}$ ----- 30 V ($I_D = 100 \mu A$)
- I_D ----- 85 A
- $R_{DS(ON)}$ ----- 2.6 mΩ max. ($V_{GS} = 10 V, I_D = 110A$)
- Q_g ----- 42.3 nC ($V_{GS} = 4.5 V, V_{DS} = 15 V, I_D = 110 A$)
- Low Total Gate Charge
- High Speed Switching
- Low On-Resistance
- Capable of 4.5 V Gate Drive
- 100 % UIL Tested
- RoHS Compliant

Package

TO-263

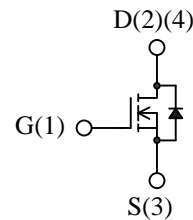


Not to scale

Applications

- DC-DC converters
- Synchronous Rectification
- Power Supplies

Equivalent circuit



Absolute Maximum Ratings

● Unless otherwise specified, $T_A = 25 \text{ }^\circ\text{C}$

| Parameter | Symbol | Test conditions | Rating | Unit |
|---|-----------|---|-------------|------------------|
| Drain to Source Voltage | V_{DS} | | 30 | V |
| Gate to Source Voltage | V_{GS} | | ± 20 | V |
| Continuous Drain Current | I_D | $T_C = 25 \text{ }^\circ\text{C}$ | 85 | A |
| Pulsed Drain Current | I_{DM} | $PW \leq 100\mu s$ Duty cycle $\leq 1 \%$ | 170 | A |
| Continuous Source Current (Body Diode) | I_S | | 85 | A |
| Pulsed Source Current (Body Diode) | I_{SM} | $PW \leq 100\mu s$ Duty cycle $\leq 1 \%$ | 170 | A |
| Single Pulse Avalanche Energy | E_{AS} | $V_{DD} = 20 V, L = 1 mH,$ $I_{AS} = 10.6 A, \text{ unclamped,}$ $R_G = 4.7 \Omega,$ Refer to Figure 1 | 170 | mJ |
| Avalanche Current | I_{AS} | | 30 | A |
| Power Dissipation | P_D | $T_C = 25 \text{ }^\circ\text{C}$ | 135 | W |
| Operating Junction Temperature | T_J | | 150 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{STG} | | - 55 to 150 | $^\circ\text{C}$ |

Thermal Characteristics

• Unless otherwise specified, $T_A = 25\text{ }^\circ\text{C}$

| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
|---|-----------------|-----------------|------|------|------|---------------------------|
| Thermal Resistance (Junction to Case) | $R_{\theta JC}$ | | – | – | 0.9 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance (Junction to Ambient) | $R_{\theta JA}$ | | – | – | 62.5 | $^\circ\text{C}/\text{W}$ |

Electrical Characteristics

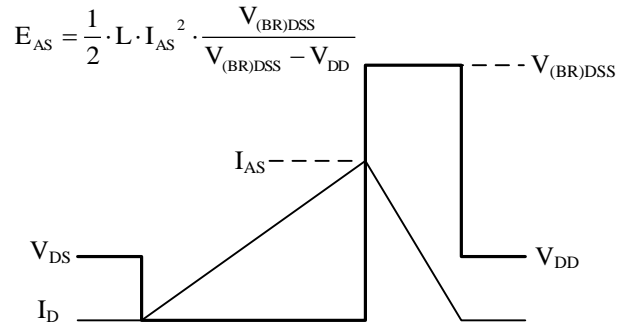
• Unless otherwise specified, $T_A = 25\text{ }^\circ\text{C}$

| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
|---|---------------|---|------|------|-----------|---------------|
| Drain to Source Breakdown Voltage | $V_{(BR)DSS}$ | $I_D = 100\text{ }\mu\text{A}$, $V_{GS} = 0\text{ V}$ | 30 | – | – | V |
| Drain to Source Leakage Current | I_{DSS} | $V_{DS} = 30\text{ V}$, $V_{GS} = 0\text{ V}$ | – | – | 100 | μA |
| Gate to Source Leakage Current | I_{GSS} | $V_{GS} = \pm 20\text{ V}$ | – | – | ± 100 | nA |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 1.5\text{ mA}$ | 1.0 | 2.0 | 2.5 | V |
| Static Drain to Source On-Resistance | $R_{DS(on)}$ | $I_D = 110\text{ A}$, $V_{GS} = 10\text{ V}$ | – | 2.1 | 2.6 | m Ω |
| | | $I_D = 55.0\text{ A}$, $V_{GS} = 4.5\text{ V}$ | – | 2.5 | 3.3 | m Ω |
| Gate Resistance | R_G | $f = 1\text{ MHz}$ | – | 0.8 | – | Ω |
| Input Capacitance | C_{iss} | $V_{DS} = 15\text{ V}$ $V_{GS} = 0\text{ V}$ $f = 1\text{ MHz}$ | – | 6200 | – | pF |
| Output Capacitance | C_{oss} | | – | 1430 | – | |
| Reverse Transfer Capacitance | C_{rss} | | – | 920 | – | |
| Total Gate Charge ($V_{GS} = 10\text{ V}$) | Q_{g1} | $V_{DS} = 15\text{ V}$ $I_D = 110\text{ A}$ | – | 91.1 | – | nC |
| Total Gate Charge ($V_{GS} = 4.5\text{ V}$) | Q_{g2} | | – | 42.3 | – | |
| Gate to Source Charge | Q_{gs} | | – | 15.1 | – | |
| Gate to Drain Charge | Q_{gd} | | – | 16.7 | – | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD} = 15\text{ V}$ $I_D = 110\text{ A}$ $V_{GS} = 10\text{ V}$, $R_G = 4.7\text{ }\Omega$ Refer to Figure 2 | – | 9.6 | – | ns |
| Rise Time | t_r | | – | 13.5 | – | |
| Turn-Off Delay Time | $t_{d(off)}$ | | – | 45.1 | – | |
| Fall Time | t_f | | – | 29.3 | – | |
| Source to Drain Diode Forward Voltage | V_{SD} | $I_S = 110\text{ A}$, $V_{GS} = 0\text{ V}$ | – | 0.9 | 1.5 | V |
| Source to Drain Diode Reverse Recovery Time | t_{rr} | $I_F = 85.0\text{ A}$ $di/dt = 100\text{ A}/\mu\text{s}$ Refer to Figure 3 | – | 43.9 | – | ns |
| Source to Drain Diode Reverse Recovery Charge | Q_{rr} | | – | 44.8 | – | nC |

Test Circuits and Waveforms



(a) Test Circuit



(b) Waveform

Figure 1 Unclamped Inductive Switching



(a) Test Circuit



(b) Waveform

Figure 2 Switching Time



(a) Test Circuit



(b) Waveform

Figure 3 Diode Reverse Recovery Time

OPERATING PRECAUTIONS

In the case that you use Sanken products or design your products by using Sanken products, the reliability largely depends on the degree of derating to be made to the rated values. Derating may be interpreted as a case that an operation range is set by derating the load from each rated value or surge voltage or noise is considered for derating in order to assure or improve the reliability. In general, derating factors include electric stresses such as electric voltage, electric current, electric power etc., environmental stresses such as ambient temperature, humidity etc. and thermal stress caused due to self-heating of semiconductor products. For these stresses, instantaneous values, maximum values and minimum values must be taken into consideration. In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature affects the reliability significantly.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5 to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of the products that have been stored for a long time.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting the products on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce excess stress.
- Volatile-type silicone greases may crack after long periods of time, resulting in reduced heat radiation effect. Silicone greases with low consistency (hard grease) may cause cracks in the mold resin when screwing the products to a heatsink.

Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

| Type | Suppliers |
|--------|--------------------------------------|
| G746 | Shin-Etsu Chemical Co., Ltd. |
| YG6260 | Momentive Performance Materials Inc. |
| SC102 | Dow Corning Toray Co., Ltd. |

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections. Ensure all test parameters are within the ratings specified by Sanken for the products.

Soldering

When soldering the products, please be sure to minimize the working time, within the following limits:

- Reflow Preheat ; 180 °C / 90 ± 30 s
 Solder heating ; 250 °C / 10 ± 1s (260 °C peak, 2 times)
- Soldering iron ; 380 ± 10 °C / 3.5 ± 0.5s (1 time)

Electrostatic Discharge

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1MΩ of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

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